

## SMD Type

Diodes

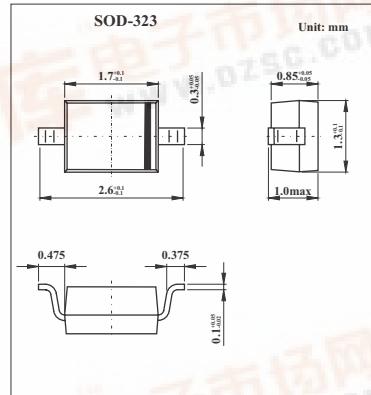
## Surface Mount Fast Switching Diode

### KAV16WS(BAV16WS)



## ■ Features

- Fast Switching Speed
- Ultra-Small Surface Mount Package
- For General Purpose Switching Applications
- High Conductance



## ■ Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit
Non-Repetitive Peak Reverse Voltage	V <sub>RM</sub>	100	V
Peak repetitive reverse voltage	V <sub>RPM</sub>		
Working peak reverse voltage	V <sub>RWM</sub>	75	V
DC blocking voltage	V <sub>R</sub>		
RMS reverse voltage	V <sub>R(RMS)</sub>	53	V
Average rectified output current	I <sub>O</sub>	150	mA
Forward Continuous Current	I <sub>FM</sub>	300	mA
Non-Repetitive Peak Forward Surge Current @ t = 1.0 μ s @ t = 1.0s	I <sub>FSM</sub>	2.0 1.0	A
Power dissipation	P <sub>D</sub>	200	mW
Typical Thermal Resistance Junction to Ambient	R <sub>θJA</sub>	325	°C/W
Operating and storage temperature range	T <sub>j</sub> , T <sub>stg</sub>	-65 to +150	°C

## ■ Electrical Characteristics Ta = 25°C

Parameter	Symbol	Testconditons	Min	Typ	Max	Unit
Reverse Breakdown Voltage	V <sub>(BR)R</sub>	I <sub>R</sub> = 1.0 μ A	75			V
Forward voltage	V <sub>FM</sub>	I <sub>F</sub> = 1.0mA I <sub>F</sub> = 10mA I <sub>F</sub> = 50mA I <sub>F</sub> = 150mA			0.745 0.855 1.0 1.25	V
Peak Reverse current	I <sub>RM</sub>	V <sub>R</sub> = 75V V <sub>R</sub> = 75V, TJ=150°C V <sub>R</sub> = 25V, TJ=150°C V <sub>R</sub> = 20V			1.0 50 30 25	μ A μ A nA nA
Junction Capacitance	C <sub>J</sub>	V <sub>R</sub> = 0, f = 1.0MHz			2.0	pF
Reverse Recovery Time	t <sub>rr</sub>	I <sub>F</sub> =I <sub>R</sub> =10mA, I <sub>rr</sub> =0.1xI <sub>R</sub> , R <sub>L</sub> =100 Ω			4.0	ns

## ■ Marking

Marking

Marking

T6 or T4

pdf.dzsc.com